

Silicon PIN Photodiode



DESCRIPTION

TEFD4300F is a silicon PIN photodiode with high radiant sensitivity in black, T-1 plastic package with daylight blocking filter. Filter bandwidth is matched with 850 nm to 950 nm IR emitters.

FEATURES

- Package type: leaded
- Package form: T-1
- Dimensions (in mm): \varnothing 3
- High radiant sensitivity
- Daylight blocking filter matched with 850 nm to 950 nm emitters
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 20^\circ$
- Package matched with IR emitter series VSLB3940, TSUS4300, and TSAL4400
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



APPLICATIONS

- High speed photo detector for data transmission
- Optical switches
- Counters and sorters
- Interrupters
- Encoders
- Position sensors

PRODUCT SUMMARY

COMPONENT	I_{ra} (μ A)	φ (deg)	$\lambda_{0.5}$ (nm)
TEFD4300F	17	± 20	770 to 1070

Note

- Test condition see table "Basic Characteristics"

ORDERING INFORMATION

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TEFD4300F	Bulk	MOQ: 5000 pcs, 5000 pcs/bulk	T-1
TEFD4300F-QS21	Tape and reel	MOQ: 10 000 pcs, 2000 pcs/reel	T-1

Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ($T_{amb} = 25^\circ\text{C}$, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V_R	60	V
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	P_V	215	mW
Junction temperature		T_j	100	$^\circ\text{C}$
Operating temperature range		T_{amb}	-40 to +100	$^\circ\text{C}$
Storage temperature range		T_{stg}	-40 to +100	$^\circ\text{C}$
Soldering temperature	$t \leq 3$ s, 2 mm from case	T_{sd}	260	$^\circ\text{C}$
Thermal resistance junction / ambient	Connected with Cu wire, 0.14 mm ²	R_{thJA}	450	K/W

BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 50\text{ mA}$	V_F	-	1	-	V
Breakdown voltage	$I_R = 100\text{ }\mu\text{A}$, $E = 0$	$V_{(BR)}$	60	-	-	V
Reverse dark current	$V_R = 10\text{ V}$, $E = 0$	I_{r0}	-	0.15	3	nA
Diode capacitance	$V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$	C_D	-	3.3	-	pF
	$V_R = 5\text{ V}$, $f = 1\text{ MHz}$, $E = 0$	C_D	-	1.2	-	pF
Open circuit voltage	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$	V_{OC}	-	350	-	mV
Temperature coefficient of V_{OC}	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$	$TK_{V_{OC}}$	-	-2.6	-	mV/K
Short circuit current	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$	I_k	-	15	-	μA
Temperature coefficient of I_k	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$	TK_{I_k}	-	0.1	-	%/K
Reverse light current	$E_e = 1\text{ mW/cm}^2$, $\lambda = 950\text{ nm}$, $V_R = 5\text{ V}$	I_{ra}	9	17	27	μA
Angle of half sensitivity		ϕ	-	± 20	-	deg
Wavelength of peak sensitivity		λ_p	-	950	-	nm
Range of spectral bandwidth		$\lambda_{0.5}$	770	-	1070	nm
Rise time	$V_R = 10\text{ V}$, $R_L = 1\text{ k}\Omega$, $\lambda = 820\text{ nm}$	t_r	-	100	-	ns
Fall time	$V_R = 10\text{ V}$, $R_L = 1\text{ k}\Omega$, $\lambda = 820\text{ nm}$	t_f	-	100	-	ns

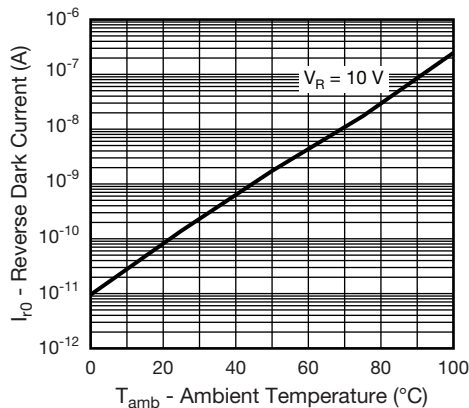
BASIC CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

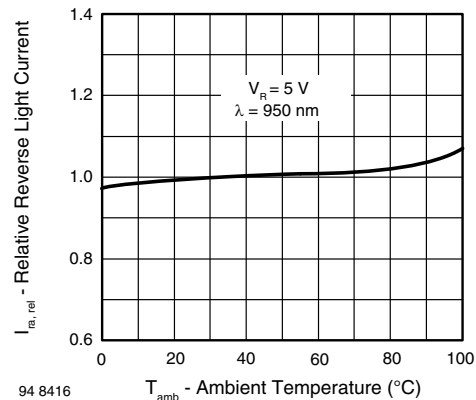


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature



Fig. 3 - Reverse Light Current vs. Irradiance

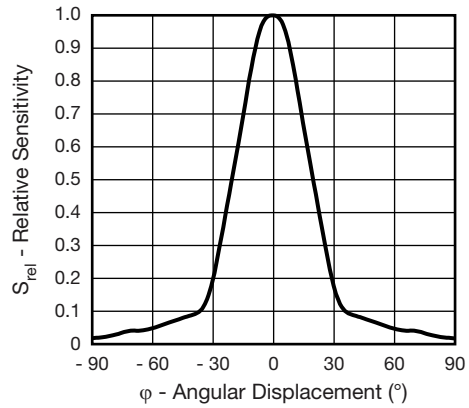


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement



Fig. 4 - Diode Capacitance vs. Reverse Voltage

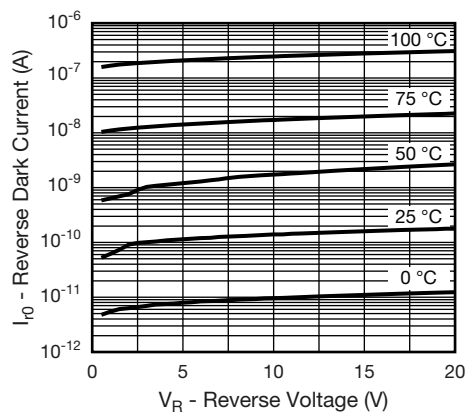


Fig. 7 - Dark Current vs. Reverse Voltage

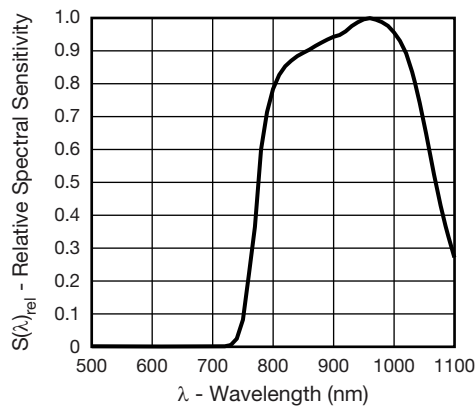
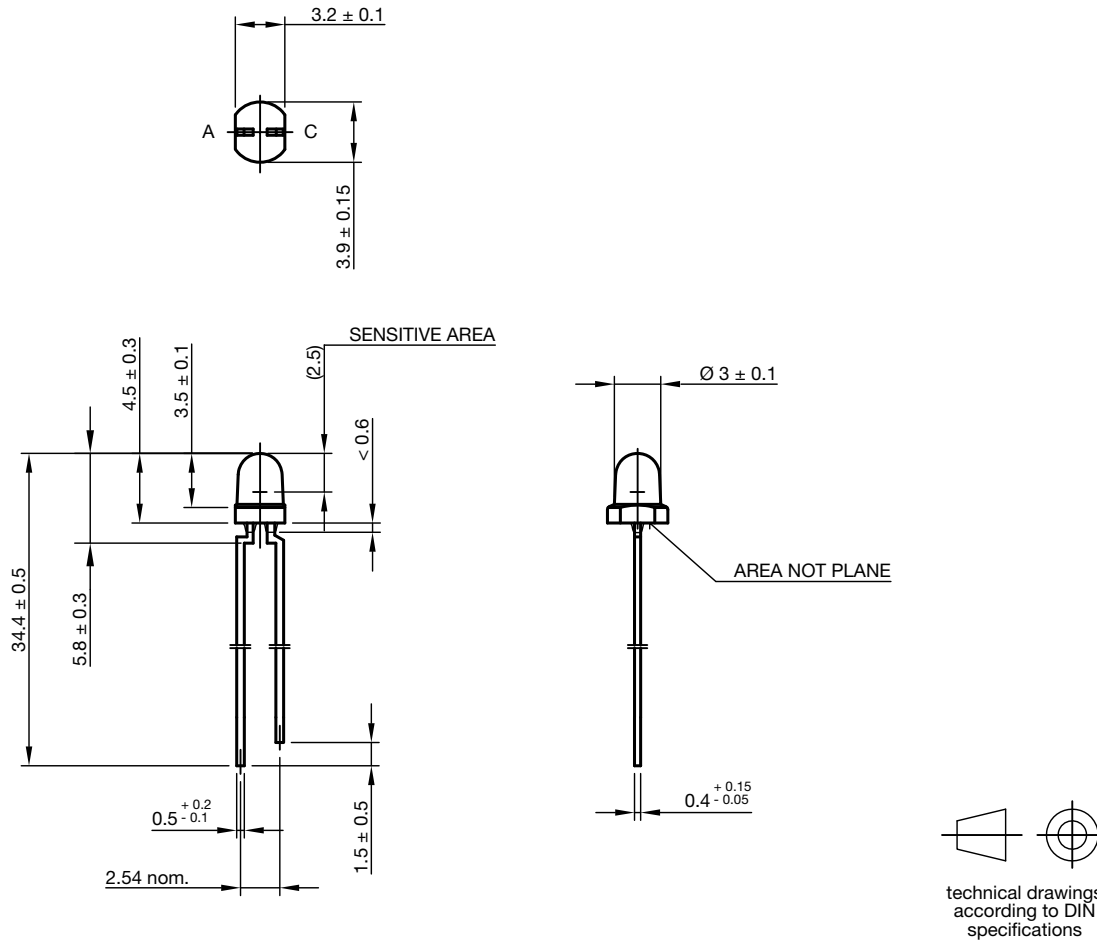


Fig. 5 - Relative Spectral Sensitivity vs. Wavelength



PACKAGE DIMENSIONS in millimeters



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